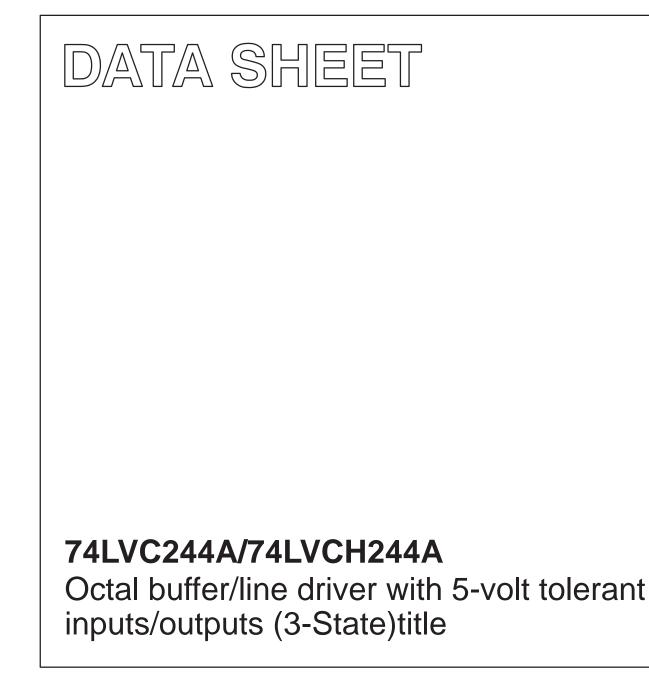
INTEGRATED CIRCUITS



Product specification Supersedes data of 1996 Sep 06 IC24 Data Handbook 1998 May 20



74LVC244A 74LVCH244A

FEATURES

- 5-volt tolerant inputs/outputs, for interfacing with 5-volt logic
- Supply voltage range of 2.7V to 3.6V
- Complies with JEDEC standard no. 8-1A
- CMOS low power consumption
- Direct interface with TTL levels
- High impedance when V_{CC} = 0V
- Bushold on all data inputs (74LVCH244A only)

DESCRIPTION

The 74LVC244A/74LVCH244A is a high-performance, low-power, low-voltage, Si-gate CMOS device, superior to most advanced CMOS compatible TTL families.

Inputs can be driven from either 3.3V or 5V devices. In 3-State operation, outputs can handle 5V. These features allow the use of these devices as translators in a mixed 3.3V/5V environment.

The 74LVC244A/74LVCH244A is an octal non-inverting buffer/line driver with 3-State outputs. The 3-State outputs are controlled by the output enable inputs 10E and 20E. A HIGH on nOE causes the outputs to assume a high impedance OFF-state. Schmitt-trigger action at all inputs makes the circuit highly tolerant for slower input rise and fall times.

The '244' is functionally identical to the '240', but the '240' has non-inverting outputs.

QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	TYPICAL	UNIT
t _{PHL} /t _{PLH}	Propagation delay $1A_n$ to $1Y_n$; $2A_n$ to $2Y_n$	$C_L = 50 pF$ $V_{CC} = 3.3V$	3.5	ns
Cl	Input capacitance		4.4	pF
C _{PD}	Power dissipation capacitance per buffer	Notes 1 and 2	22.6	pF

NOTE:

1. C_{PD} is used to determine the dynamic power dissipation (P_D in μ W):

 $P_D = C_{PD} \times V_{CC}^2 \times f_i + \Sigma (C_L \times V_{CC}^2 \times f_o)$ where: $f_i = \text{input frequency in MHz}; C_L = \text{output load capacity in pF};$ $f_o = \text{output frequency in MHz}; V_{CC} = \text{supply voltage in V};$

 Σ (C_L x V_{CC}² x f_o) = sum of outputs. 2. The condition is $V_I = GND$ to V_{CC}

ORDERING INFORMATION

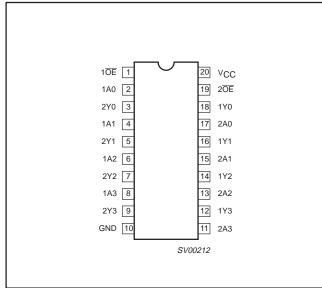
PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	PKG. DWG. #
20-Pin Plastic Shrink Small Outline (SO)	–40°C to +85°C	74LVC244A D	74LVC244A D	SOT163-1
20-Pin Plastic Shrink Small Outline (SSOP) Type II	–40°C to +85°C	74LVC244A DB	74LVC244A DB	SOT339-1
20-Pin Plastic Thin Shrink Small Outline (TSSOP) Type I	–40°C to +85°C	74LVC244A PW	7LVC244APW DH	SOT360-1
20-Pin Plastic Shrink Small Outline (SO)	–40°C to +85°C	74LVCH244A D	74LVCH244A D	SOT163-1
20-Pin Plastic Shrink Small Outline (SSOP) Type II	–40°C to +85°C	74LVCH244A DB	74LVCH244A DB	SOT339-1
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74LVC244A 74LVCH244A

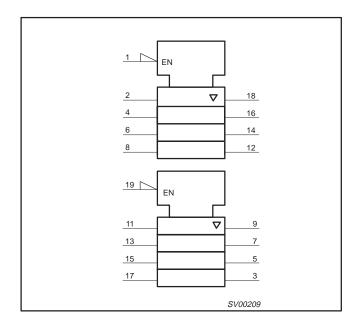
PIN DESCRIPTION

PIN NUMBER	SYMBOL	FUNCTION
1	1 0E	Output enable input (active LOW)
2, 4, 6, 8	$1A_0$ to $1A_{'3}$	Data inputs
3, 5, 7, 9	$2Y_0$ to $2Y_3$	Bus outputs
10	GND	Ground (0V)
17, 15, 13, 11	$2A_0$ to $2A_3$	Bus inputs
18, 16, 14, 12	$1Y_0$ to $1Y_3$	Bus outputs
19	20E	Output enable input (active-LOW)
20	V _{CC}	Positive supply voltage

PIN CONFIGURATION



LOGIC SYMBOL (IEEE/IEC)



FUNCTION TABLE

INP	JTS	OUTPUT
nOE	nA _n	nY _n
L	L	L
L	Н	Н
Н	Х	Z

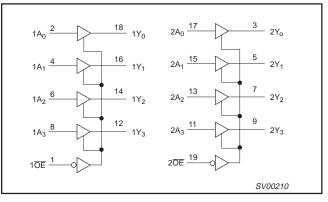
H = HIGH voltage level

L = LOW voltage level

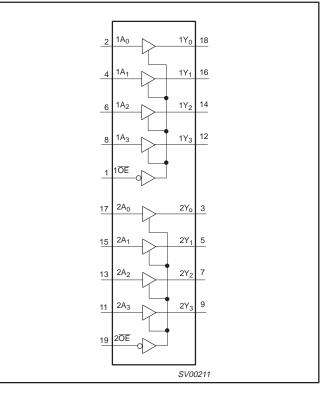
X = Don't care

Z = High impedance OFF-state

LOGIC SYMBOL



FUNCTIONAL DIAGRAM



74LVC244A 74LVCH244A

RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	CONDITIONS	LIM	UNIT	
STMBOL	PARAMETER	CONDITIONS	MIN	MAX	UNIT
N	DC supply voltage (for max. speed performance)		2.7	3.6	v
V _{CC}	DC supply voltage (for low-voltage applications)		1.2	3.6	V
VI	DC Input voltage range		0	5.5	V
Vo	DC Output voltage range; output HIGH or LOW state		0	V _{CC}	V
	DC output voltage range; output 3-State		0	5.5	
T _{amb}	Operating ambient temperature range in free-air		-40	+85	°C
t _r , t _f	Input rise and fall times	$V_{CC} = 1.2 \text{ to } 2.7 \text{V}$ $V_{CC} = 2.7 \text{ to } 3.6 \text{V}$	0 0	20 10	ns/V

ABSOLUTE MAXIMUM RATINGS¹

In accordance with the Absolute Maximum Rating System (IEC 134) Voltages are referenced to GND (ground = 0V)

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V _{CC}	DC supply voltage		-0.5 to +6.5	V
I _{IK}	DC input diode current	V _I <0	-50	mA
VI	DC input voltage	Note 2	-0.5 to +6.5	V
I _{OK}	DC output diode current	$V_{O} > V_{CC} \text{ or } V_{O} < 0$	±50	mA
)/	DC output voltage; output HIGH or LOW state	Note 2	-0.5 to V _{CC} +0.5	N/
Vo	DC output voltage; output 3-State	Note 2	-0.5 to 6.5	V
Ι _Ο	DC output source or sink current	$V_{O} = 0$ to V_{CC}	±50	mA
I _{GND} , I _{CC}	DC V _{CC} or GND current		±100	mA
T _{stg}	Storage temperature range		-65 to +150	°C
P _{TOT}	Power dissipation per package – plastic mini-pack (SO) – plastic shrink mini-pack (SSOP and TSSOP)	above +70°C derate linearly with 8 mW/K above +60°C derate linearly with 5.5 mW/K	500 500	mW

NOTES:

 Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

2. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

DC ELECTRICAL CHARACTERISTICS

Over recommended operating conditions voltages are referenced to GND (ground = 0V)

			L	LIMITS			
SYMBOL	PARAMETER	TEST CONDITIONS	Temp = -	40°C to	+85°C		
			MIN	TYP ¹	MAX	1	
M		V _{CC} = 1.2V				V	
VIH	HIGH level Input voltage	V _{CC} = 2.7 to 3.6V	2.0			1 [×]	
M		$V_{CC} = 1.2V$			GND	V	
VIL	LOW level Input voltage	V _{CC} = 2.7 to 3.6V			0.8	1 [×]	
		$V_{CC} = 2.7V; V_I = V_{IH} \text{ or } V_{IL}; I_O = -12mA$	V _{CC} -0.5				
N/		$V_{CC} = 3.0V; V_I = V_{IH} \text{ or } V_{IL}; I_O = -100 \mu A$	V _{CC} -0.2	V _{CC}			
V _{OH}	HIGH level output voltage	$V_{CC} = 3.0V; V_I = V_{IH} \text{ or } V_{IL}; I_O = -18\text{mA}$	V _{CC} -0.6			1 [×]	
		$V_{CC} = 3.0V; V_I = V_{IH} \text{ or } V_{IL;} I_O = -24\text{mA}$	V _{CC} -0.8			1	
		$V_{CC} = 2.7V; V_I = V_{IH} \text{ or } V_{IL}; I_O = 12mA$			0.40		
V _{OL}	LOW level output voltage	$V_{CC} = 3.0V; V_I = V_{IH} \text{ or } V_{IL}; I_O = 100 \mu A$		GND	0.20	V	
		$V_{CC} = 3.0V; V_I = V_{IH} \text{ or } V_{IL;} I_O = 24mA$			0.55	1	
lj –	Input leakage current	$V_{CC} = 3.6V; V_I = 5.5V \text{ or GND}$		±0.1	±5	μA	
I _{OZ}	3-State output OFF-state current	$V_{CC} = 3.6V; V_I = V_{IH} \text{ or } V_{IL}; V_O = 5.5V \text{ or GND}$		0.1	±5	μA	
I _{off}	Power off leakage supply	$V_{CC} = 0.0V; V_{I} \text{ or } V_{O} = 5.5V$		0.1	±10	μA	
I _{CC}	Quiescent supply current	$V_{CC} = 3.6V; V_I = V_{CC} \text{ or GND}; I_O = 0$		0.1	10	μA	
ΔI_{CC}	Additional quiescent supply current per input pin	V_{CC} = 2.7V to 3.6V; V_{I} = V_{CC} –0.6V; I_{O} = 0		5	500	μA	
I _{BHL}	Bushold LOW sustaining current ^{2, 3, 4}	V _{CC} = 3.0V; V _I =0.8V	75	-	-	μA	
I _{BHH}	Bushold HIGH sustaining current ^{2, 3, 4}	V _{CC} = 3.0V; V _I =2.0V	-75	-	-	μΑ	
I _{BHLO}	Bushold LOW overdrive current2, 3, 5	V _{CC} = 3.6V	500	-	-	μA	
I _{BHHO}	Bushold HIGH overdrive current2, 3, 5	V _{CC} = 3.6V	-500	-	-	μA	

NOTES:

1. All typical values are at $V_{CC} = 3.3V$ and $T_{amb} = 25^{\circ}C$. 2. Valid for data inputs of bushold parts (LVCH-A) only. 3. For data inputs only, control inputs do not have a bushold circuit

4. The specified sustaining current at the data inputs do not have a bushold circuit.

The specified overdrive current at the data input forces the data input to the opposite logic input state.
For bushold parts, the bushold circuit is switched off when V_I exceeds V_{CC} allowing 5.5V on the input terminal.

74LVC244A 74LVCH244A

Product specification

74LVC244A 74LVCH244A

AC CHARACTERISTICS

GND = 0V; $t_r = t_f \le 2.5$ ns; $C_L = 50$ pF; $R_L = 500\Omega$; $T_{amb} = -40^{\circ}$ C to +85°C.

					l	LIMITS			
SYMBOL	PARAMETER	WAVEFORM	Vcc	; = 3.3V ±0).3V	V _{CC} =	= 2.7V	V _{CC} = 1.2V	UNIT
			MIN	TYP ¹	MAX	MIN	MAX	ТҮР	
t _{PHL} t _{PLH}	Propagation delay 1A _n to 1Y _n ; 2A _n to 2Y _n	1, 3	1.5	3.5	5.9	1.5	6.9	16.0	ns
t _{PZH} t _{PZL}	$\frac{3-\text{State output enable time}}{10E} \text{ to } 1Y_n;$ 20E to $2Y_n$	2, 3	1.5	4.3	7.6	1.5	8.6	19.0	ns
t _{PHZ} t _{PLZ}	$\begin{array}{c} \mbox{3-State output disable time} \\ \hline 10E \mbox{ to } 1Y_n; \\ \hline 20E \mbox{ to } 2Y_n \end{array}$	2, 3	1.5	3.7	5.8	1.5	6.8	17.0	ns

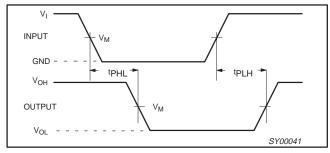
NOTE:

1. Unless otherwise stated, all typical values are at V_{CC} = 3.3V and T_{amb} = 25°C.

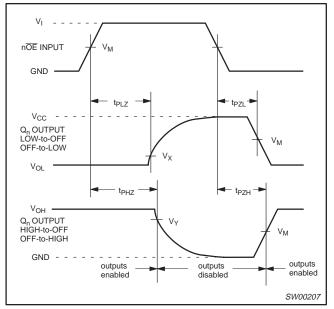
AC WAVEFORMS

 V_M = 1.5 V at $V_{CC} \geq$ 2.7 V; V_M = 0.5 $~V_{CC}$ at V_{CC} < 2.7 V $~V_{OL}$ and $~V_{OH}$ are the typical output voltage drop that occur with the output load.

 V_X = V_{OL} + 0.3V at V_{CC} \geq 2.7V; V_X = V_{OL} + 0.1 V_{CC} at V_{CC} < 2.7V V_Y = V_{OH} – 0.3V at V_{CC} \geq 2.7V; V_Y = V_{OH} – 0.1 V_{CC} at V_{CC} < 2.7V

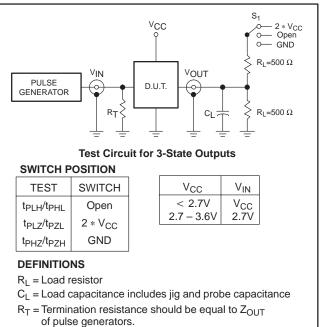






Waveform 2. 3-State enable and disable times.

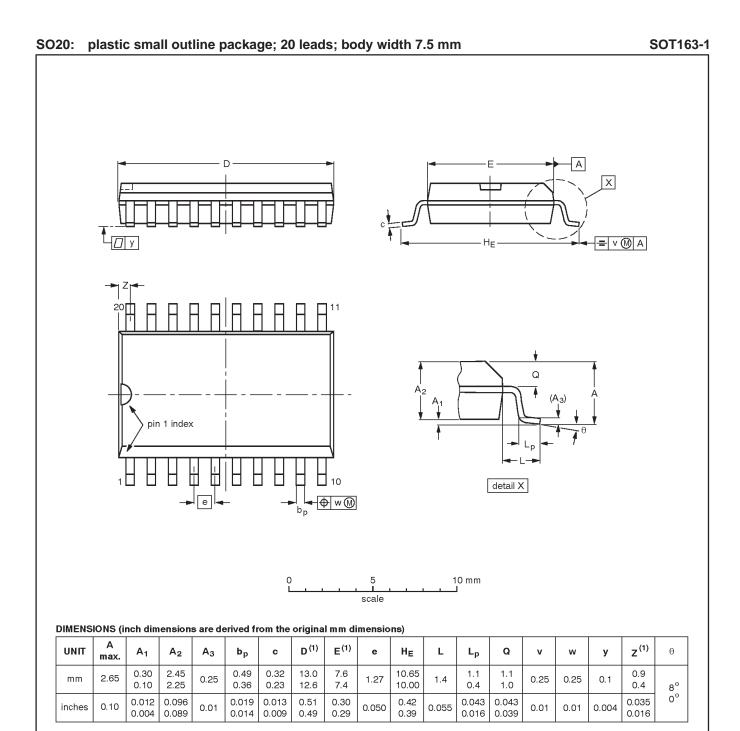
TEST CIRCUIT





Waveform 3. Load circuitry for switching times.

74LVC244A 74LVCH244A

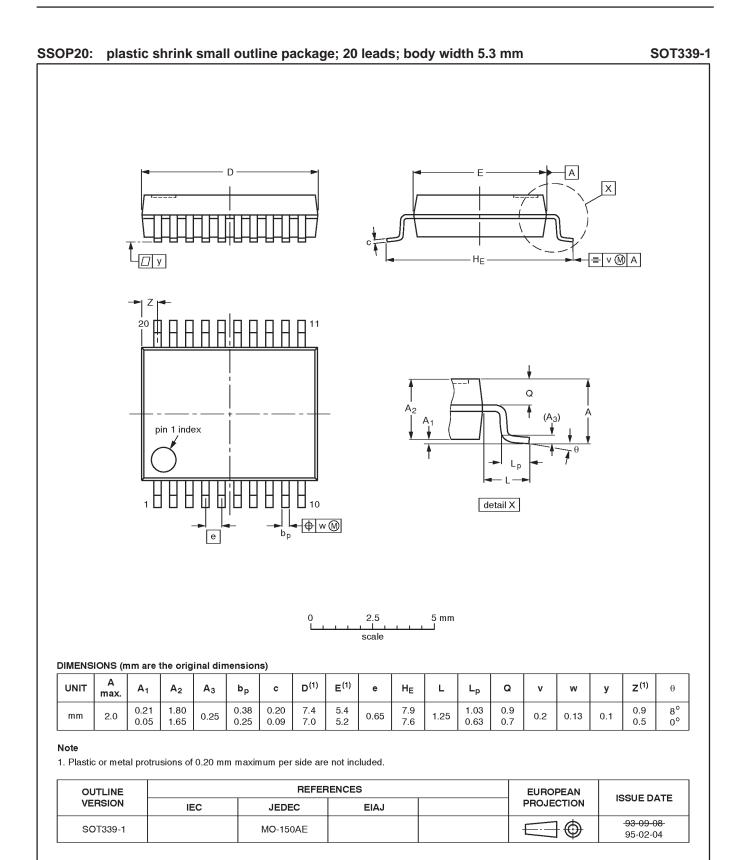


Note

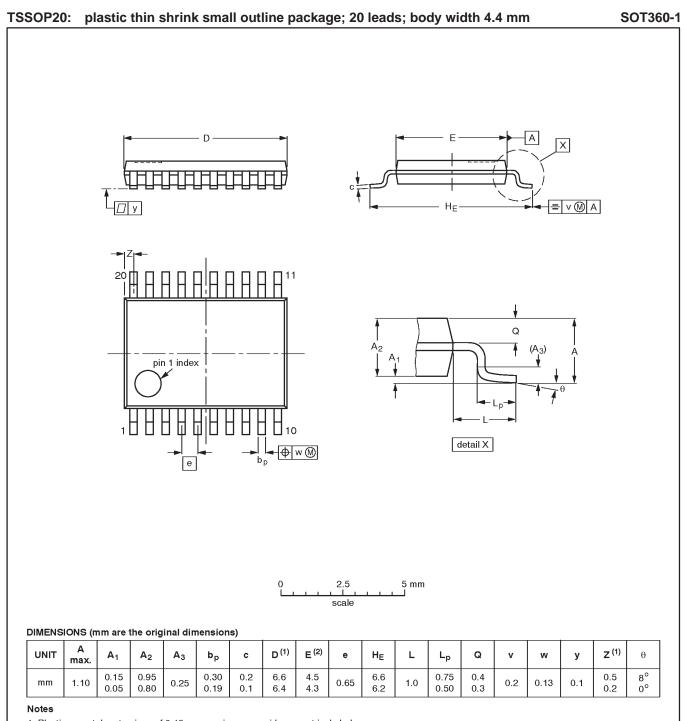
1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.

OUTLINE	REFERENCES			EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE
SOT163-1	075E04	MS-013AC				-92-11-17 95-01-24

74LVC244A 74LVCH244A



74LVC244A 74LVCH244A



1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.

2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE	REFERENCES					
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE
SOT360-1		MO-153AC				-93-06-16 95-02-04

Data sheet status

Data sheet status	Product status	Definition [1]
Objective specification	Development	This data sheet contains the design target or goal specifications for product development. Specification may change in any manner without notice.
Preliminary specification	Qualification	This data sheet contains preliminary data, and supplementary data will be published at a later date. Philips Semiconductors reserves the right to make chages at any time without notice in order to improve design and supply the best possible product.
Product specification	Production	This data sheet contains final specifications. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product.

[1] Please consult the most recently issued datasheet before initiating or completing a design.

Definitions

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Limiting values definition - Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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